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EXPEDITED PROCEDURE  
UNDER 37 C.F.R. §1.116

ATC 12815  
#17  
Amended  
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1/20/03  
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2/11/03

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Makoto SASAKI

Serial No.: 09/532,892

Group Art Unit: 2815

Filed: March 22, 2000

Examiner: P. Brock, II

For: SEMICONDUCTOR DEVICE WITH COPPER FUSE SECTION

Honorable Commissioner of Patents  
Washington, D.C. 20231

**AMENDMENT UNDER 37 C.F.R. §1.116**

Sir:

In response to the Office Action dated September 30, 2002, please amend the above-identified application as follows:

**IN THE CLAIMS:**

**Please cancel claims 17-19 and 26-28 without prejudice or disclaimer.**

**Please amend claims 1 and 20 as follows:**

- D'
1. (Four Times Amended) A semiconductor memory device, including a copper fuse section that is oxidized by a laser beam in an oxidizing environment, comprising:
    - a dielectric film including a first film section formed on a substrate, a second film section formed on said first film section, and a third film section formed over said second film section;
    - a wiring line structure, including:
      - a first and a second wiring line, each of said first and second wiring lines formed directly upon said second film section of said dielectric film without an intervening film